

## Fast Recovery Rectifiers

**Reverse Voltage - 400 V**

**Forward Current - 20 A**

### Features

- ◆The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆Glass passivated junction chip
- ◆Low profile package
- ◆High forward surge current capability
- ◆High temperature soldering guaranteed 260 C/10 seconds at terminals

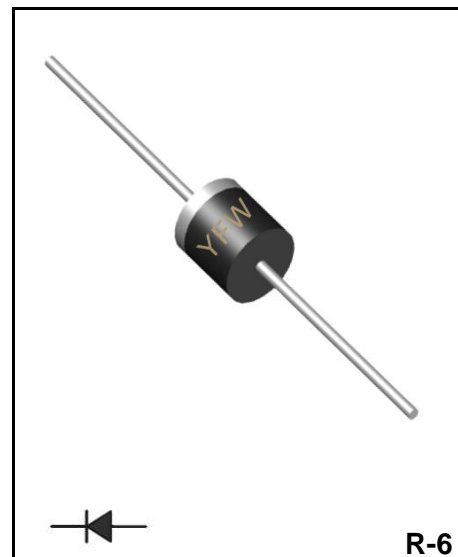
### Mechanical Data

- ◆Case: R-6
- ◆Terminals: Solderable per MIL-STD-202, Method 208
- ◆Approx. Weight: 2.05g / 0.072oz

### Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.



Parameter	Symbols	FR2004	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	400	V
Maximum RMS voltage	$V_{RMS}$	280	V
Maximum DC Blocking Voltage	$V_{DC}$	400	V
Maximum Average Forward Rectified Current at $T_c = 100\text{ }^{\circ}\text{C}$	$I_{F(AV)}$	20.0	A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	$I_{FSM}$	500	A
Maximum Instantaneous Forward Voltage at 20A	$V_F$	1.0	V
Maximum DC Reverse Current $T_a = 25\text{ }^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_a = 125\text{ }^{\circ}\text{C}$	$I_R$	5.0 200	$\mu\text{A}$
Maximum reverse recovery time(Note 1)	$T_{rr}$	500	nS
Typical Junction Capacitance(Note 2)	$C_j$	150	pF
Typical Thermal Resistance	$R_{\theta JA}$	15	$^{\circ}\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{stg}$	-65 ~ +150	$^{\circ}\text{C}$

Note:1,Reverse recovery time test condition:  $I_F=0.5\text{A}$   $I_R=1.0\text{A}$   $I_{rr}=0.25\text{A}$

2.Measured at 1MHz and applied reverse voltage of 4.0V D.C

FIG.1-TYPICAL FORWARD CHARACTERISTIC

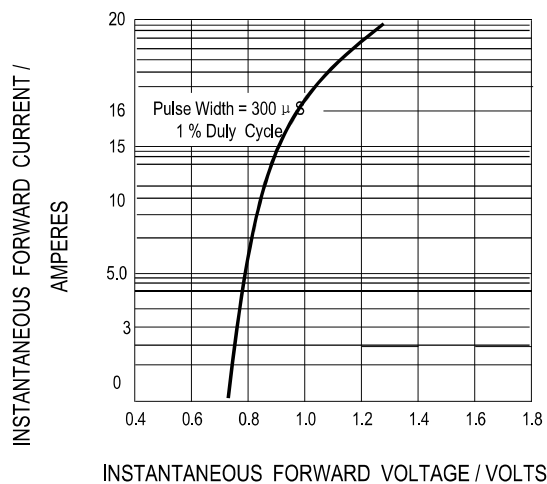


FIG. 2 -- TYPICAL JUNCTION CAPACITANCE

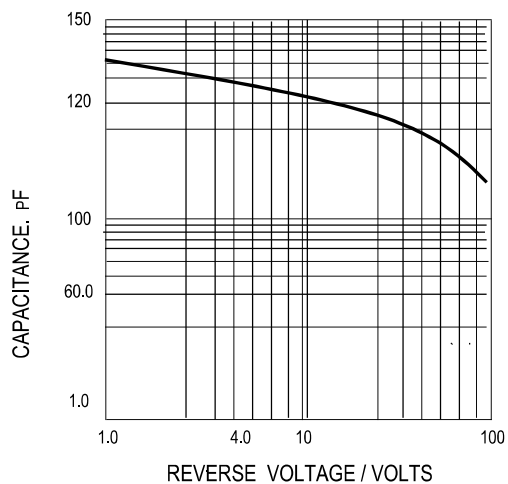


FIG. 3 -- FORWARD CURRENT DERATING CURVE

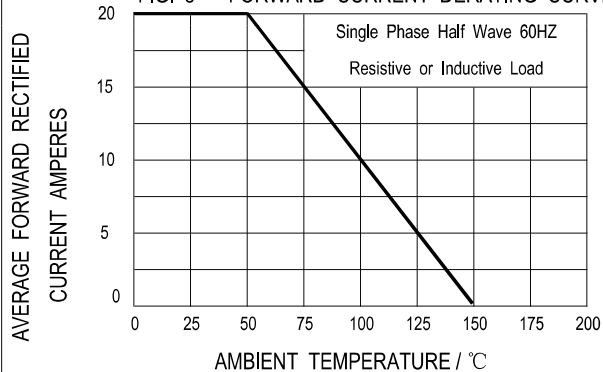


FIG. 4 – PEAK FORWARD SURGE CURRENT

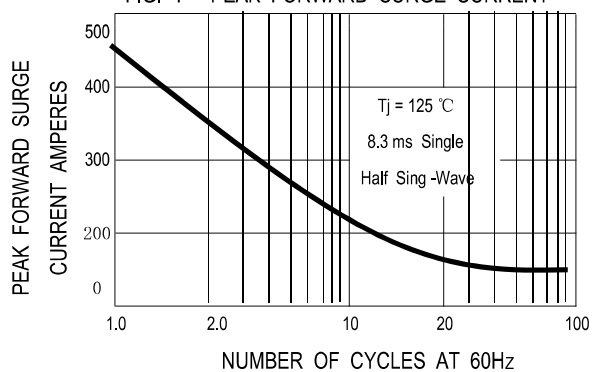
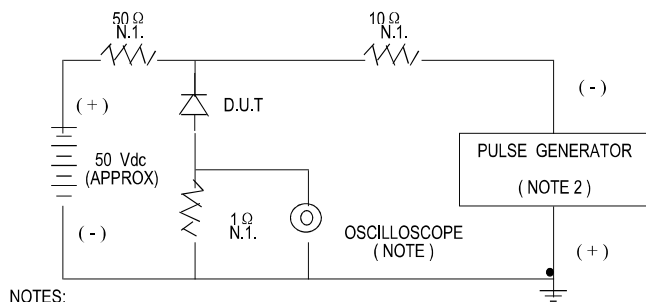
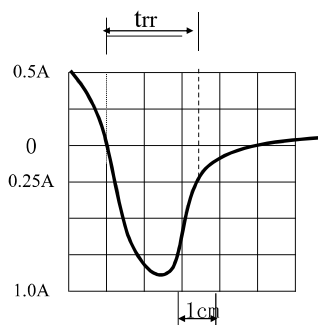


FIG. 5 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES:

1. RISE TIME = 7n SEC MAX. INPUT IMPEDANCE = 1 MEGOHM, 22PF
2. RISE TIME = 10n SEC MAX. SOURCE IMPEDANCE = 50 OHM.



SET TIME BASE FOR 50 / 100 ns / cm

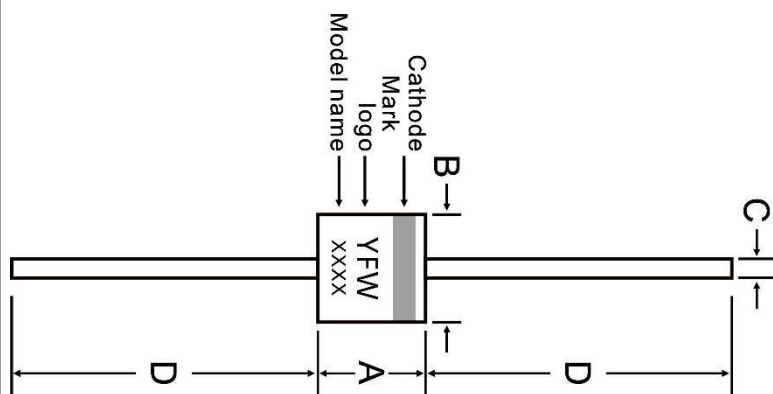
### Ordering information

Package	Packing Description	Packing Quantity
R-6	bulk	100PCS/Inner Box 5000PCS/Carton
	ammo pack	500PCS/Box 5000PCS/Carton

### Package Dimensions

#### R-6

Dim.	Millimeter(mm)		INCHES	
	Min.	Max.	Min.	Max.
A	8.60	9.10	0.340	0.360
B	8.60	9.10	0.340	0.360
C	1.20	1.30	0.048	0.052
D	25.40	-	1.00	-



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